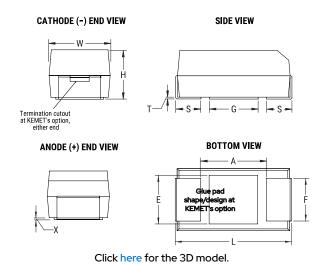


# T495V336K010AHE100

T495, Tantalum, MnO2 Tantalum, Commercial Grade, 33 uF, 10%, 10 VDC, SMD, MnO2, Molded, Low Profile, Low ESR, 100 mOhms, 7343, 2 mm, 1.3



General Information		
Series	T495	
Dielectric	MnO2 Tantalum	
Style	SMD Chip	
Description	SMD, MnO2, Molded, Low Profile, Low ESR	
Features	Low ESR	
RoHS	No	
Prop 65	WARNING: Cancer and reproductive harm - https://www.p65warnings.ca.gov /	
SCIP Number	1dd2e1b8-26dd-4d52-927c-6f9 d519011aa	
Termination	Tin Lead (SnPb)	
AEC-Q200	No	
Typical Component Weight	286.4 mg	
Shelf Life	156 Weeks	
MSL	1	

33 uF

10 VDC (85C), 6.7 VDC (125C)

10%

Dimensions	
L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
Н	1.8mm +/-0.2mm
Т	0.13mm REF
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm
A	3.6mm MIN
E	3.5mm REF
G	3.5mm REF
X	0.05mm REF

Packaging

**Packaging Quantity** 

T&R, 178mm

1000

Т	0.13mm REF	Temperature Range	-55/+125°C
S	1.3mm +/-0.3mm	Rated Temperature	85°C
F	2.4mm +/-0.1mm	Dissipation Factor	6% 120Hz 25C
A	3.6mm MIN	Failure Rate	N/A
E	3.5mm REF	ESR	100 mOhms (100kHz 25C)
G	3.5mm REF	Ripple Current	1118 mA (rms, 100kHz 25C), 1006.2 mA (rms, 85C), 447.2 mA (rms, 125C)
X	0.05mm REF		
		Leakage Current	3.3 uA (5min 25°C)
Packaging Specifications			

**Specifications** 

Capacitance Tolerance

Voltage DC

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

Generated 05/04/2025 © 2006 - 2025 YAGEO

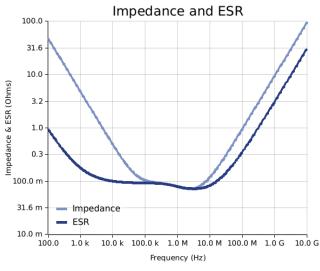


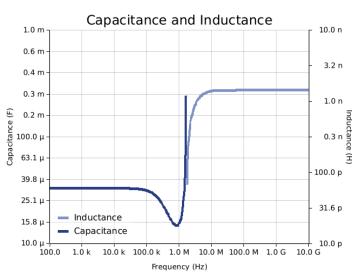
## T495V336K010AHE100

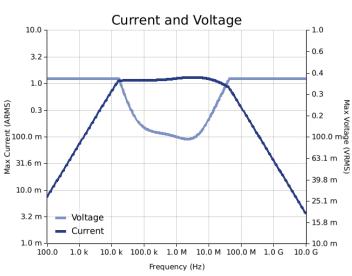
T495, Tantalum, MnO2 Tantalum, Commercial Grade, 33 uF, 10%, 10 VDC, SMD, MnO2, Molded, Low Profile, Low ESR, 100 mOhms, 7343, 2 mm, 1.3 mm

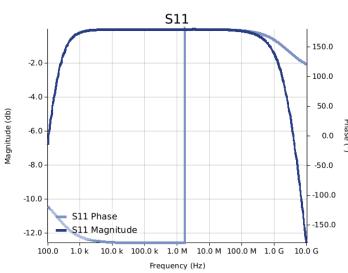
### **Simulations**

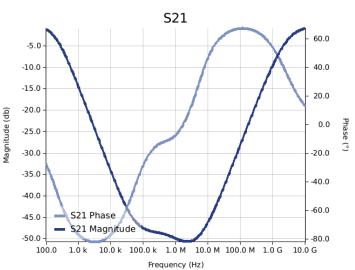
For the complete simulation environment please visit K-SIM.











Generated 05/04/2025 © 2006 - 2025 YAGEO



### T495V336K010AHE100

T495, Tantalum, MnO2 Tantalum, Commercial Grade, 33 uF, 10%, 10 VDC, SMD, MnO2, Molded, Low Profile, Low ESR, 100 mOhms, 7343, 2 mm, 1.3

#### These are simulations.

This is not a specification!

The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

The responses shown do not represent a specified or implied maximum capability of the device for all applications.

- The ESR used for ripple "Ripple Current/Voltage vs. Frequency" plots is the ESR at ambient temperature.

- The ESR in the "Temperature Rise vs. Ripple Current" plots is adjusted to each incremental temperature rise before the power and ripple current is calculated.
  The effects shown herein are based on measured data from a multiple part sample of the parts in question.
  Ripple capability of this device will be factored by thermal resistance (Rth) created by circuit traces (addi affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.
  The peak voltages generated in the "Temperature Rise vs. Combined Ripple Currents" plot are calculated for each frequency and are not combined with voltages
- generated at any other harmonics.

   Please consult with the catalog or field applications engineer for maximum capability of the device in specific applications.

All product information and data (collectively, the "Information") are subject to change without notice.

KEMET K-SIM is designed to simulate behavior of components with respect to frequency, ambient temperature, and DC bias levels. The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation effects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

All Information given herein is believed to be accurate and reliable, but is presented without guarantee, warranty, or responsibility of any kind, expressed or implied. Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute – and we specifically disclaim – any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

If you have any questions please contact K-SIM.

Generated 05/04/2025 © 2006 - 2025 YAGEO